

J176 P-CHANNEL JFET



Linear Systems replaces discontinued Siliconix J176 The J176 is a single P-Channel JFET switch

This p-channel analog switch is designed to provide low on-resistance and fast switching. When used in combination with the complimentary J/SST111 n-channel family, the J176 simplifies series-shunt switching applications

J176 Benefits:

- Low Error Voltage
- High-Speed Analog Circuit Performance
- Negligible "Off-Error," Excellent Accuracy
- Good Frequency Response
- Eliminates Additional Buffering

J176 Applications:

- Analog Switches
- Choppers
- Sample-and-Hold
- Normally "On" Switches
- Current Limiters

FEATURES					
DIRECT REPLACEMENT FOR SILICONIX J176					
LOW ON RESISTANCE	$r_{DS(on)} \le 250\Omega$				
LOW GATE OPERATING CURRENT	$I_{D(off)} = 10pA$				
FAST SWITCHING	t _(ON) 25ns				
ABSOLUTE MAXIMUM RATINGS					
@ 25°C (unless otherwise noted)					
Maximum Temperatures					
Storage Temperature	-55°C to +150°C				
Operating Junction Temperature	-55°C to +135°C				
Maximum Power Dissipation					
Continuous Power Dissipation	350mW				
MAXIMUM CURRENT					
Gate Current (Note 1)	I _G = -50mA				
MAXIMUM VOLTAGES					
Gate to Drain Voltage	$V_{GDS} = 30V$				
Gate to Source Voltage	$V_{GSS} = 30V$				

J176 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
BV_{GSS}	Gate to Source Breakdown Voltage	30				$I_{G} = -1\mu A$, $V_{DS} = 0V$
$V_{GS(F)}$	Gate to Source Forward Voltage		- <u>0.7</u>		V	$I_G = -1mA$, $V_{DS} = 0V$
V _{GS(off)}	Gate to Source Cutoff Voltage	1	4-	4		$V_{DS} = -15V, I_{D} = -10nA$
I _{DSS}	Drain to Source Saturation Current	-2		-35		$V_{DS} = -15V, V_{GS} = 0V$
I _{GSS}	Gate Reverse Current	-	0.01	1		$V_{GS} = 20V, V_{DS} = 0V$
l _G	Gate Operating Current		0.01		nA	$V_{DG} = -15V, I_{D} = -1mA$
I _{D(off)}	Drain Cutoff Current		-0.01	-1		$V_{DS} = -15V, V_{GS} = 0V$
r _{DS(on)}	Drain to Source On Resistance			250	Ω	$V_{GS} = 0V_{OS} - 0.1V$

J176 SWITCHING CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC		UNITS	CONDITIONS
t _{d(on)}	Turn On Time	10		$V_{GS}(L) = 0V$
t _r	Turn On Rise Time	15	ns	V _{GS} (H) = 10V
t _{d(off)}	Turn Off Time	10	113	See Switching Circuit
t _f	Turn Off Fall Time	20		g .

Note 1 - Absolute maximum ratings are limiting values above which J176 serviceability may be impaired.

J176 SWITCHING CIRCUIT PARAMETERS

V _{DD}	-6V
V_{GG}	8V
R _L	1800Ω
R_{G}	390Ω
I _{D(on)}	-3mA

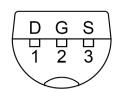
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TO-92 (Bottom View)

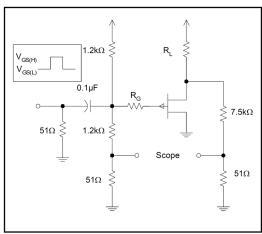


Available Packages:

J176 in TO-92 J176 in bare die.

Please contact Micross for full package and die dimensions

SWITCHING CIRCUIT



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